

MPSA42
MPSA43

**SILICON
HIGH VOLTAGE
NPN TRANSISTORS**



TO-92 CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR MPSA42 and MPSA43 are silicon NPN transistors designed for high voltage applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^{\circ}\text{C}$)

Collector-Base Voltage
Collector-Emitter Voltage
Emitter-Base Voltage
Continuous Collector Current
Power Dissipation
Power Dissipation ($T_C=25^{\circ}\text{C}$)
Operating and Storage Junction Temperature
Thermal Resistance
Thermal Resistance

SYMBOL	MPSA42	MPSA43	UNITS
V_{CBO}	300	200	V
V_{CEO}	300	200	V
V_{EBO}	6.0		V
I_C	500		mA
P_D	625		mW
P_D	1.5		W
T_J, T_{stg}	-65 to +150		$^{\circ}\text{C}$
Θ_{JA}	200		$^{\circ}\text{C/W}$
Θ_{JC}	83.3		$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^{\circ}\text{C}$)

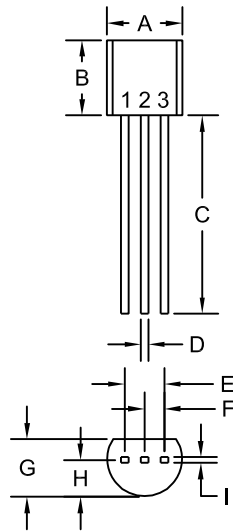
SYMBOL	TEST CONDITIONS	MPSA42		MPSA43		UNITS
		MIN	MAX	MIN	MAX	
I_{CBO}	$V_{CB}=200\text{V}$	-	100	-	-	nA
I_{CBO}	$V_{CB}=160\text{V}$	-	-	-	100	nA
I_{EBO}	$V_{EB}=6.0\text{V}$	-	100	-	-	nA
I_{EBO}	$V_{EB}=4.0\text{V}$	-	-	-	100	nA
BV_{CBO}	$I_C=100\mu\text{A}$	300	-	200	-	V
BV_{CEO}	$I_C=1.0\text{mA}$	300	-	200	-	V
BV_{EBO}	$I_E=100\mu\text{A}$	6.0	-	6.0	-	V
$V_{CE(SAT)}$	$I_C=20\text{mA}, I_B=2.0\text{mA}$	-	0.50	-	0.40	V
$V_{BE(SAT)}$	$I_C=20\text{mA}, I_B=2.0\text{mA}$	-	0.90	-	0.90	V
h_{FE}	$V_{CE}=10\text{V}, I_C=1.0\text{mA}$	25	-	25	-	
h_{FE}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	40	-	40	-	
h_{FE}	$V_{CE}=10\text{V}, I_C=30\text{mA}$	40	-	50	200	
f_T	$V_{CE}=20\text{V}, I_C=10\text{mA}, f=100\text{MHz}$	50	-	50	-	MHz
C_{ob}	$V_{CB}=20\text{V}, I_E=0, f=1.0\text{MHz}$	-	3.0	-	4.0	pF

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TO-92 CASE - MECHANICAL OUTLINE



R1

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.175	0.205	4.45	5.21
B	0.170	0.210	4.32	5.33
C	0.500	-	12.70	-
D	0.016	0.022	0.41	0.56
E	0.100		2.54	
F	0.050		1.27	
G	0.125	0.165	3.18	4.19
H	0.080	0.105	2.03	2.67
I	0.015		0.38	

TO-92 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING:

FULL PART NUMBER

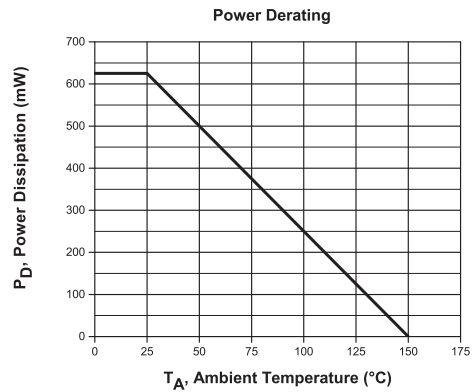
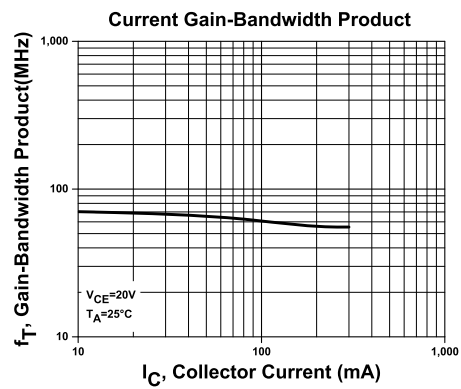
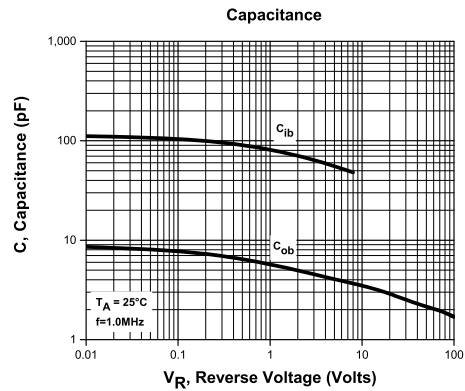
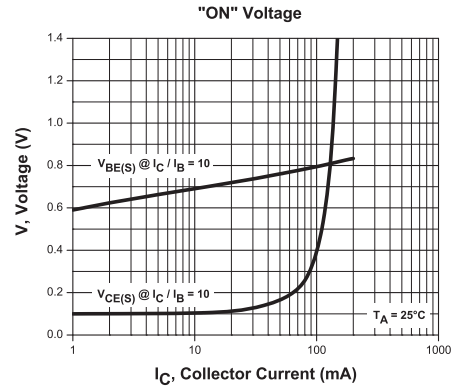
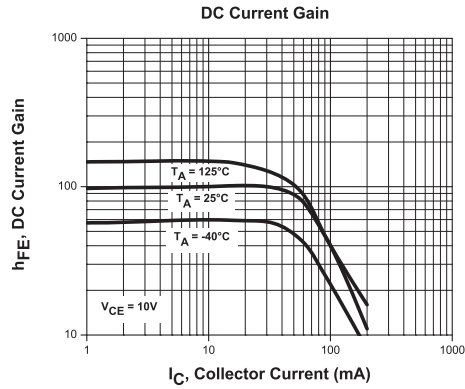
R2 (26-March 2015)

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TYPICAL ELECTRICAL CHARACTERISTICS



R2 (26-March 2015)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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